



DOCKET NO: 246155US2SRD

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :
MASATO KOYAMA, ET AL. : EXAMINER: HU, S.
SERIAL NO: 10/726,705 :
FILED: DECEMBER 4, 2003 : GROUP ART UNIT: 2811
FOR: A METHOD OF FORMING A :
SEMICONDUCTOR DEVICE HAVING
AN AMORPHOUS/CRYSTALLINE GATE
INSULATING LAYER

AMENDMENT UNDER 37 C.F.R. § 1.111

COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

SIR:

In response to the Office Action dated September 20, 2005, please amend the above-identified application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 5 of this paper.